SPEED ENHANCED DAMPING OUTPUT CIRCUIT

Technical Field of the Invention

This invention relates to output circuits, and more particularly relates to output circuits designed to reduce undershoot and overshoot of the output signal.

Background of the Invention

Output circuits are used widely in the semiconductor industry. Their general purpose is to take a signal to be provided as an output from one circuit and provide it as an input to another circuit. In the process, the signal is typically buffered and amplified so that the signal is delivered with minimum delay and with sufficient amplitude to drive the receiving circuit.

One problem with output circuits, especially when designed for minimum latency (delay), is that they tend to suffer from undershoot and overshoot. That is, as the signal is driven from low to high, it tends to go over (overshoot) the target high voltage before settling to the target voltage, while, conversely, as the signal is driven from high to low, it tends to go under (undershoot) the target low voltage before settling to the target voltage.

A common prior art approach to minimizing undershoot and overshoot is to provide a damping resistor in the output circuit. While the damping resistor does improve the undershoot/overshoot problem, and also aides in increasing the impedance of the output driver, the damping effect results in a decrease in output drive strength and it increases the propagation delay in delivering the signal from one circuit to the next.

An improvement over simply providing a damping resistor in the output circuit is disclosed in U.S. Patent No. 6,137,322, which is entitled "Dynamic Output Circuit" and which is commonly assigned. In this approach, an

additional transistor is coupled in parallel with a high side output transistor, and an additional transistor is also coupled in parallel with a low side transistor. In both the high side and low side outputs, between the respective high side and low side output transistors and their associated additional parallel-coupled transistor is placed a transmission gate that is controlled by feedback from the output node. This solution alleviates the problems of overshoots and undershoots, while providing fast propagation delays. However, it requires a number of additional components to implement the feedback circuitry.

Another approach to the undershoot/overshoot problem is disclosed in U.S. Patent No. 6,300,815, which is entitled "Voltage Reference Overshoot Protection Circuit" and which is commonly assigned. In this approach, a voltage reference overshoot protection circuit senses unwanted ringing voltage levels in a driven device, such as a backplane, and controls the gate voltage to a voltage level control transistor such that a ringing output signal produced by an associated output driver is reduced in response to a control signal dependent on the ringing voltage level. This also requires a number of additional components, to implement the voltage reference overshoot protection circuit. Also, this approach is a clamping type solution, rather than a damping type solution.

Summary of the Invention

The present invention provides an improved output circuit that provides the desired damping effect, while maintaining a minimal propagation delay. In accordance with the present invention there is provided an output circuit having undershoot/overshoot reduction, and improved propagation delay. A damping control circuit branch is provided, including a resistor and a diode connected in parallel between a first node and a second node, the second node being coupled to an output node. An output transistor, having a gate, is coupled by its source and drain between a power supply and the second node. A predriver circuit is adapted to receive an input signal and provide a voltage at the gate.

These and other features of the invention will be apparent to those skilled in the art from the following detailed description of the invention, taken together with the accompanying drawings.

Brief Description of the Drawings

Fig. 1 is a circuit diagram of a preferred embodiment of the present invention.

Fig. 2 is a graph showing output signal level over time, illustrating improved propagation delay achievable with the embodiment of Fig. 1.

Detailed Description of the Preferred Embodiment

The numerous innovative teachings of the present invention will be described with particular reference to the presently preferred exemplary embodiments. However, it should be understood that this class of embodiments provides only a few examples of the many advantageous uses and innovative teachings herein. In general, statements made in the specification of the present application do not necessarily delimit the invention, as set forth in different aspects in the various claims appended hereto. Moreover, some statements may apply to some inventive aspects, but not to others.

Figure **1** is a circuit diagram of a preferred embodiment output circuit **10** of the present invention. The circuit **10** has three parts, an upper predriver **11**, a lower predriver **12** and a speed-enhanced damping circuit **13**. The circuit uses p-type metal oxide semiconductor (PMOS) and n-type metal oxide semiconductor (NMOS) transistors. In general, diodes are used to substantially short out a damping resistor during the initial phase of a transition. The circuit **10** provides low impedance, i.e., high dynamic current, through the AC threshold of the device being driven by circuit **10**, e.g., Vcc/2. Once the initial phase of the transition is complete, and the transition has overcome the voltage drop of the diode, the diode discontinues shorting out the damping resistor and restores the damping effect (increasing the impedance) to the output driver during the critical phase of the transition. This solution provides a decrease in propagation delay while preserving the damping resistor effect. In fact, the undershoot/overshoot benefit is comparable to that of a circuit employing only a damping resistor. It also reduces skew rates over process, temperature range, and Vcc.

In circuit **10**, an input signal is provided at node **in** to the gate of PMOS transistors **MP2** and **MP4** and to the gate of NMOS transistors **MN1** and **MN4**. The source of transistor **MP2** is connected to its backgate and to power

supply at voltage Vcc, while its drain is connected at node **S1** to the drain of transistor **MN1**. The source of transistor MN1 is connected at node **S2** to the drain of NMOS transistor **MN2**, the source of which is connected to ground. A tristate enable signal is provided at a tristate input node **tri** to the gate of PMOS transistor **MP3**, to the gate of NMOS transistor **MN3** and to the input of an inverter **XTRI**. The source of transistor **MP3** is connected to Vcc, while its drain is connected at node **S4** to the source of transistor **MP4**. The drain of transistor **MP4** is connected at node **S5** to the drain of transistor **MN4**, while the source of transistor **MN4** is connected to ground. The output of inverter **XTRI** is connected at node **S3** to the gate of PMOS transistor **MP1** and to the gate of transistor **MN2**. The source of transistor **MP1** is connected to its backgate and to Vcc, while its drain is connected to node **S1**. Node **S1** is connected to the gate of a PMOS high side output transistor **MUOP**, while node **S5** is connected to the gate of an NMOS low side output transistor **MLOP**. The source of transistor **MUOP** is connected to its backgate and to Vcc, while its drain is connected to one node of a branch comprising parallel connected resistor **RH** and diode **DH**, with the anode of diode **DH** being connected to the drain of transistor **MUOP**, and the cathode of diode **DH** being connected to the other node of the branch, which node is also the output node **out** of the circuit. The source of transistor **MLOP** is connected to ground, while its drain is connected to one node of a branch comprising parallel connected resistor **RL** and diode **DL**, with the cathode of diode **DL** being connected to the drain of transistor **MLOP**, and the cathode of diode **DL** being connected to the other node of the branch, which node is also the output node **out** of the circuit.

The output circuit **10** operates in two modes, normal mode and tri-state mode. In normal mode, the signal at node **tri** is low, thus driving the gate of transistor **MN3** low, turning it off, and also driving the gate of transistor **MP3** low, thus turning it on, and through inverter **XTRI**, driving the gate of transistor

MP1 (node **S3**) high and turning it off. Thus, transistors **MN3** and **MP1** do not operate during normal mode.

When input signal at node **in** is driven high, the gates of transistors **MP2** and **MP4**, and of transistors **MN1** and **MN4**, are driven high. Thus, transistors **MP2** and **MP4** are turned off. Conversely, transistors **MN1** and **MN4** are turned on. This pulls nodes **S1** and **S5** low. This, in turn, turns transistor **MUOP** on, while turning transistor **MLOP** off. Thus, the output at node **out** is pulled high through the branch comprising parallel connected resistor **RH** and diode **DH**. In the initial phase of the transition of the output signal from low to high, diode **DH** conducts and provides a very low impedance path, effectively shorting out resistor **RH**. However, once the initial phase of the transition is complete, and the voltage drop across the diode no longer exceeds its threshold, the diode turns off and discontinues shorting out the damping resistor, thus restoring the damping effect of resistor **RH**. This increases the impedance of the output driver during the critical phase of the transition.

Again in normal mode, when input signal at node **in** is driven low, the gates of transistors **MP2** and **MP4** , and of transistors **MN1** and **MN4**, are driven low. Thus, transistors **MP2** and **MP4** are turned on. Conversely, transistors **MN1** and **MN4** are turned off. This pulls nodes **S1** and **S5** high. This, in turn, turns transistor **MUOP** off, while turning transistor **MLOP** on. Thus, the output **out** is pulled low through the branch comprising parallel connected resistor **RL** and diode **DL**. In the initial phase of the transition of the output signal from low to high, diode **DL** conducts and provides a very low impedance path, effectively shorting out resistor **RL**. However, once the initial phase of the transition is complete, and the voltage drop across the diode no longer exceeds its threshold, the diode turns off and discontinues shorting out the damping resistor, thus restoring the damping effect of resistor

RH. This increases the impedance of the output driver during the critical phase of the transition.

During tri-state mode, the signal at node **tri** is high, thus driving the gate of transistor **MN3** high, turning it on, and also driving the gate of transistor **MP3** high, thus turning it off, and through inverter **XTRI**, driving the gate of transistor **MP1** (node **S3**) low and turning it on. With transistor **MP1** on, node **S1** is pulled high, thus turning off transistor **MUOP**. With transistor **MN3** on, node **S5** is pulled low, thus turning off transistor **MLOP**. With transistors **MUOP** and **MLOP** off, the output is in tri-state.

Figure **2** is a graph of signal level versus time, and illustrates the damping effect of the circuit of Figure **1**, compared with a typical prior art circuit employing only damping resistors. Curve **21** is the input signal, while curve **22** is the output signal of a circuit employing only a damping resistor and curve **23** is the output signal of the circuit of Figure **1**, both for circuits fabricated in a strong process, with a maximum Vcc. Curve **24** is the output signal of a circuit employing only a damping resistor and curve **25** is the output signal of the circuit of Figure **1**, both for circuits fabricated in a weak process, with a minimum Vcc.

Although the present invention and its advantages have been described in detail, it should be understood that various changes, substitutions and alterations can be made herein without departing from the spirit and scope of the invention as defined by the appended claims. For example, while the preferred embodiment shown in Figure 1 includes tristate circuitry, the invention may be implemented in output circuits not employing tristate circuitry. By way of another example, while the preferred embodiment shown in Figure 1 includes pull-up and pull-down circuitry, in the form of upper predriver and transistor MUOP and lower predriver and transistor MLOP, the present invention may be implemented in output circuits employing only pull-up circuitry, or only pull-down circuitry.